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1 Electrical ratings

Table 2: Absolute maximum ratings

		Value	•	
Symbol	Parameter	TO-220, DPAK, IPAK	TO-220FP	Unit
V _{DS}	Drain-source voltage	800		V
V _G s	Gate-source voltage	±30		V
1-	Drain current (continuous) at T _C = 25 °C	2.5 2.5 ⁽¹⁾ 1.57 1.57 ⁽¹⁾		Α
l _D	Drain current (continuous) at T _C = 100 °C			Α
I _{DM} ⁽²⁾	Drain current (pulsed)	10	10 ⁽¹⁾	Α
Ртот	Total dissipation at T _C = 25 °C	70	25	W
ESD	Gate-source, human body model, R = 1.5 k Ω , C = 100 pF	2		kV
dv/dt ⁽³⁾	Peak diode recovery voltage slope	4.5		V/ns
Viso	Insulation withstand voltage (RMS) from all three leads to external heat sink (t = 1 s, T_C = 25 °C)		2.5	kV
T _{stg}	Storage temperature range	-55 to 150		°C
Tj	Operation junction temperature range			

Notes:

Table 3: Thermal data

Symbol Parameter		Value					
Symbol	raiametei	TO-220	TO-220FP	DPAK	IPAK	Unit	
R _{thj-case}	Thermal resistance junction-case	1.78	5	1.78		°C/W	
R _{thj-amb}	Thermal resistance junction-ambient	62.5			100	°C/W	
R _{thj-pcb} ⁽¹⁾	Thermal resistance junction-pcb			50		°C/W	

Notes:

Table 4: Avalanche characteristics

Symbol	Symbol Parameter			
I _{AR}	Avalanche current, repetitive or non-repetitive (pulse width limited by T _{J max})			
E _{AS}	Single pulse avalanche energy (starting $T_J = 25$ °C, $I_D = I_{AR}$, $V_{DD} = 50$ V)	170	mJ	



⁽¹⁾This value is limited by package.

 $[\]ensuremath{^{(2)}}\mbox{Pulse}$ width is limited by safe operating area.

 $^{^{(3)}}$ I_{SD} ≤ 2.5 A, di/dt ≤ 200 A/ μ s, V_{DS(peak)} < V(BR)DSS, V_{DD} = 640 V

⁽¹⁾When mounted on FR-4 board of 1 inch², 2 oz Cu.

2 Electrical characteristics

(T_C = 25 °C unless otherwise specified)

Table 5: On /off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	V _{GS} = 0 V, I _D = 1 mA	800			V
	Zara gata valtaga drain	V _{GS} = 0 V, V _{DS} = 800 V			1	μΑ
IDSS	Zero gate voltage drain current	$V_{GS} = 0 \text{ V}, V_{DS} = 800 \text{ V},$ $T_{C} = 125 \text{ °C}^{(1)}$			50	μΑ
Igss	Gate-body leakage current	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	μΑ
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}$, $I_D = 50 \mu A$	3	3.75	4.5	V
R _{DS(on)}	Static drain-source on- resistance	V _{GS} = 10 V, I _D = 1.25 A		3.8	4.5	Ω

Notes:

Table 6: Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{iss}	Input capacitance		ı	485	-	pF
Coss	Output capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V},$ $f = 1 \text{ MHz}$	1	57	-	pF
C_{rss}	Reverse transfer capacitance	1 – 1 101112	1	11	-	pF
Coss eq ⁽¹⁾	Equivalent output capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 0 \text{ to } 640 \text{ V}$	1	22	-	pF
Q_g	Total gate charge	$V_{DD} = 640 \text{ V}, I_D = 2.5 \text{ A},$	1	19	-	nC
Q_{gs}	Gate-source charge	V _{GS} = 0 to 10 V	ı	3.2	-	nC
Q_{gd}	Gate-drain charge	(see Figure 17: "Test circuit for gate charge behavior")	-	10.8	-	nC

Notes:

Table 7: Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time	V _{DD} = 400 V, I _D = 1.25 A, R _G = 4.7	-	17	-	ns
tr	Rise time	Ω, V _{GS} =10 V (see Figure 16: "Test circuit for resistive load switching times" and		27	-	ns
t _{d(off)}	Turn-off delay time			36	-	ns
t _f	Fall time	Figure 21: "Switching time waveform")	-	40	-	ns



⁽¹⁾Defined by design, not subject to production test.

 $^{^{(1)}}$ Coss eq is defined as a constant equivalent capacitance giving the same charging time as Coss when Vps increases from 0 to 80%

Table 8: Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{SD}	Source-drain current		-		2.5	Α
I _{SDM} ⁽¹⁾	Source-drain current (pulsed)		-		10	Α
V _{SD} ⁽²⁾	Forward on voltage	I _{SD} = 2.5 A, V _{GS} = 0 V	-		1.6	V
t _{rr}	Reverse recovery time	$I_{SD} = 2.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	384		ns
Qrr	Reverse recovery charge	$V_{DD} = 50 \text{ V}$	-	1.6		μC
I _{RRM}	Reverse recovery current	(see Figure 18: "Test circuit for inductive load switching and diode recovery times")	-	8.4		А
t _{rr}	Reverse recovery time	$I_{SD} = 2.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$	-	474		ns
Qrr	Reverse recovery charge	V _{DD} = 50 V , T _J = 150 °C	-	2.1		μC
I _{RRM}	Reverse recovery current	(see Figure 18: "Test circuit for inductive load switching and diode recovery times")	-	8.8		Α

Notes:

Table 9: Gate-source Zener diode

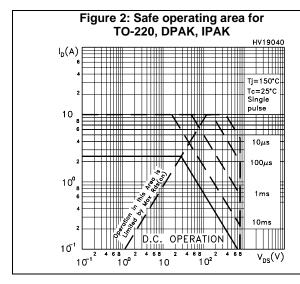
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _(BR) GSO	Gate-source breakdown voltage	I _{GS} = ±1 mA (open drain)	30	-	-	V

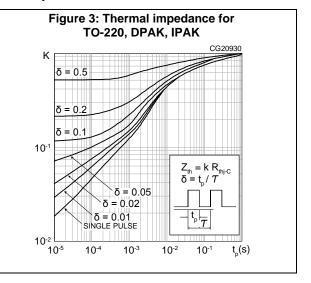
The built-in back-to-back Zener diodes are specifically designed to enhance the ESD performance of the device. The Zener voltage facilitates efficient and cost-effective device integrity protection, thus eliminating the need for additional external componentry.

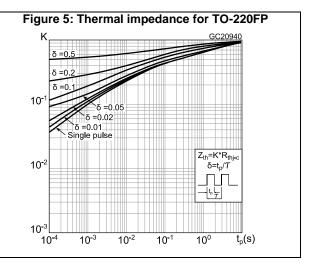
 $^{^{(1)}\}text{Pulsed:}$ pulse duration = 300 $\mu\text{s,}$ duty cycle 1.5%.

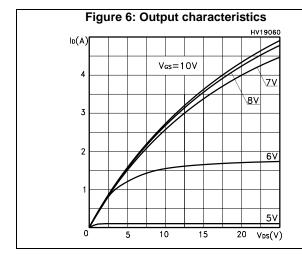
⁽²⁾Pulse width is limited by safe operating area.

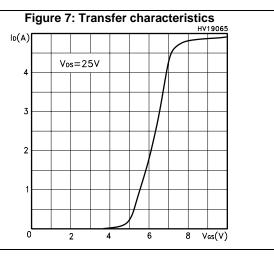
2.1 Electrical characteristics (curves)



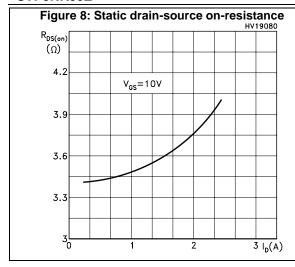


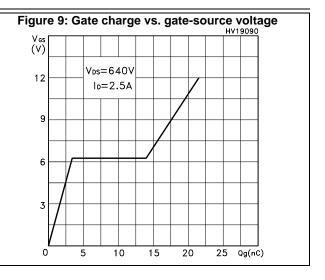


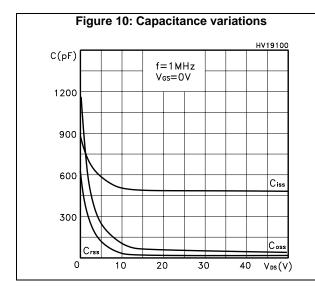


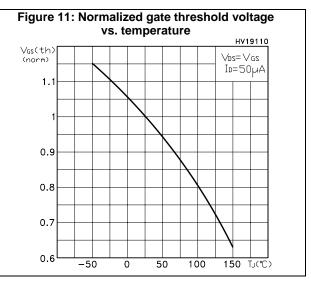


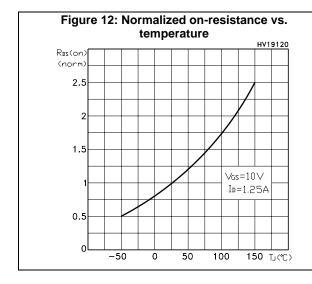
57

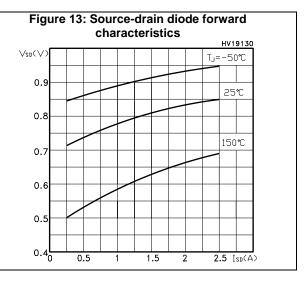


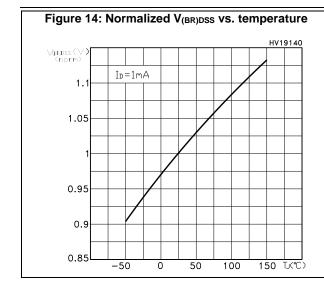


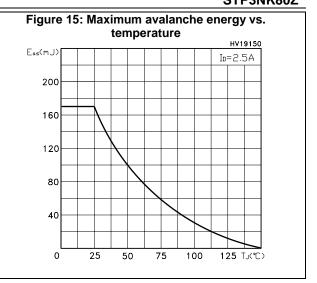




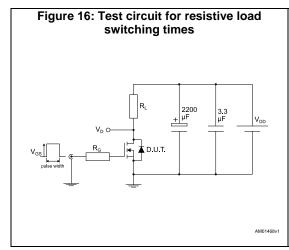


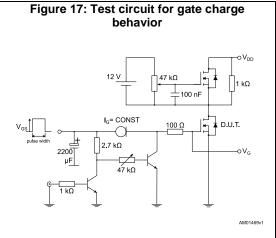


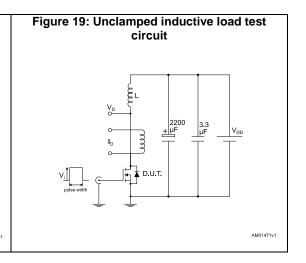


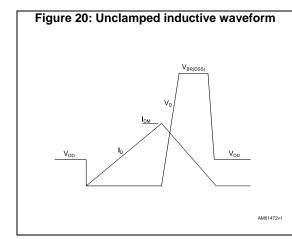


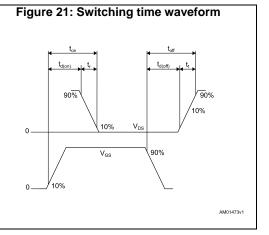
3 Test circuits











\7/

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

4.1 IPAK (TO-251) type A package information

L2 D b2(3x)**b** (3x) A 1 B5 e 0068771_IK_typeA_rev14 e 1

Figure 22: IPAK (TO-251) type A package outline

Table 10: IPAK (TO-251) type A package mechanical data

D:		mm				
Dim.	Min.	Тур.	Max.			
А	2.20		2.40			
A1	0.90		1.10			
b	0.64		0.90			
b2			0.95			
b4	5.20		5.40			
B5		0.30				
С	0.45		0.60			
c2	0.48		0.60			
D	6.00		6.20			
E	6.40		6.60			
е		2.28				
e1	4.40		4.60			
Н		16.10				
L	9.00		9.40			
L1	0.80		1.20			
L2		0.80	1.00			
V1		10°				

4.2 DPAK package information

4.2.1 DPAK (TO-252) type A package information

Figure 23: DPAK (TO-252) type A package outline

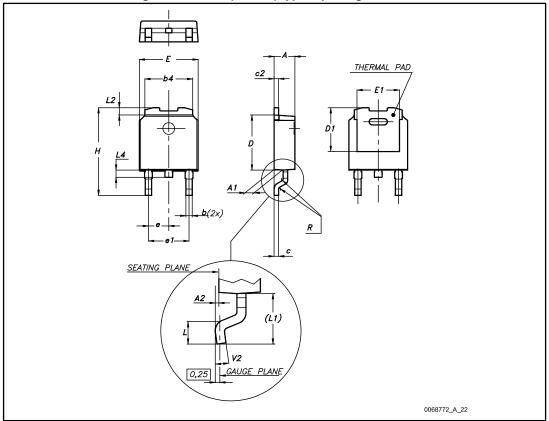


Table 11: DPAK (TO-252) type A mechanical data

Table 11: DPAK (10-252) type A mechanical data						
Dim		mm				
Dim.	Min.	Тур.	Max.			
Α	2.20		2.40			
A1	0.90		1.10			
A2	0.03		0.23			
b	0.64		0.90			
b4	5.20		5.40			
С	0.45		0.60			
c2	0.48		0.60			
D	6.00		6.20			
D1	4.95	5.10	5.25			
Е	6.40		6.60			
E1	4.60	4.70	4.80			
е	2.16	2.28	2.40			
e1	4.40		4.60			
Н	9.35		10.10			
L	1.00		1.50			
(L1)	2.60	2.80	3.00			
L2	0.65	0.80	0.95			
L4	0.60		1.00			
R		0.20				
V2	0°		8°			

Figure 24: DPAK (TO-252) type A recommended footprint (dimensions are in mm)

4.2.2 DPAK (TO-252) type C2 package information

Figure 25: DPAK (TO-252) type C2 package outline

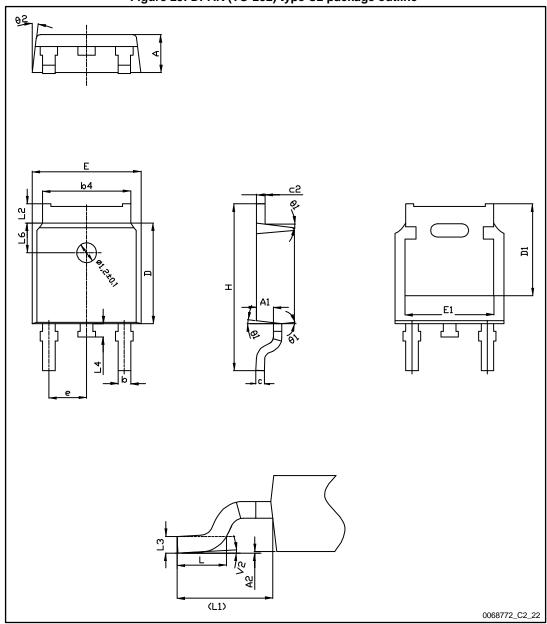


Table 12: DPAK (TO-252) type C2 mechanical data

	mm			
Dim.	Min.	Тур.	Max.	
А	2.20	2.30	2.38	
A1	0.90	1.01	1.10	
A2	0.00		0.10	
b	0.72		0.85	
b4	5.13	5.33	5.46	
С	0.47		0.60	
c2	0.47		0.60	
D	6.00	6.10	6.20	
D1	5.10		5.60	
E	6.50	6.60	6.70	
E1	5.20		5.50	
е	2.186	2.286	2.386	
Н	9.80	10.10	10.40	
L	1.40	1.50	1.70	
L1		2.90 REF		
L2	0.90		1.25	
L3		0.51 BSC		
L4	0.60	0.80	1.00	
L6		1.80 BSC		
θ1	5°	7°	9°	
θ2	5°	7°	9°	
V2	0°		8°	

Figure 26: DPAK (TO-252) type C2 recommended footprint (dimensions are in mm)

4.2.3 DPAK (TO-252) type E package information

Figure 27: DPAK (TO-252) type E package outline

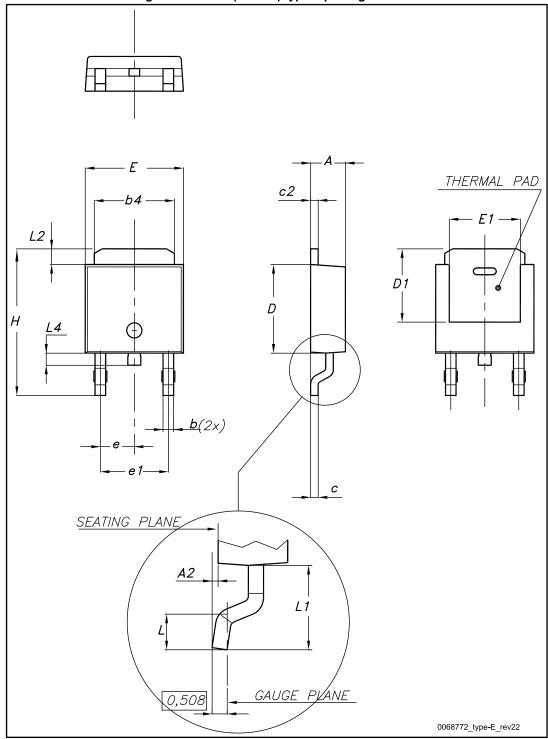
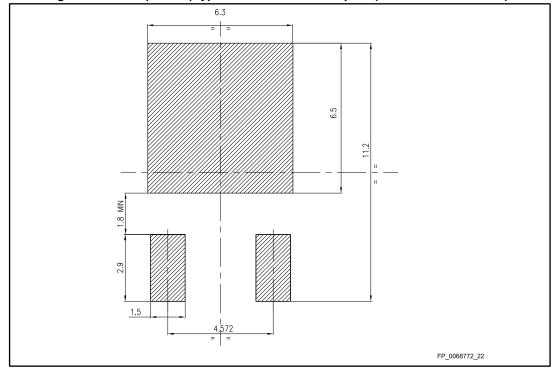


Table 13: DPAK (TO-252) type E mechanical data

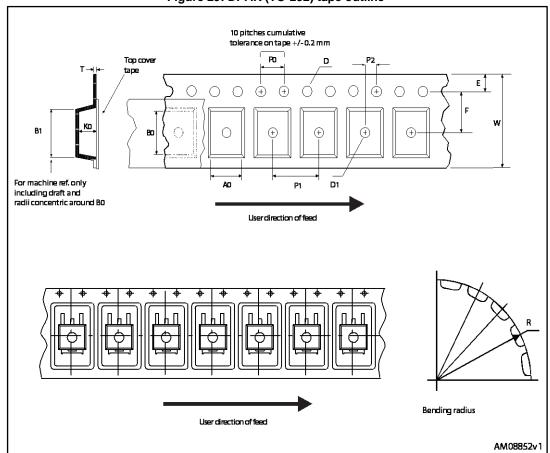
	143.6 10.217.11(10.2.	52) type E mechanical da	-u	
Dim.	mm			
	Min.	Тур.	Max.	
Α	2.18		2.39	
A2			0.13	
b	0.65		0.884	
b4	4.95		5.46	
С	0.46		0.61	
c2	0.46		0.60	
D	5.97		6.22	
D1	5.21			
E	6.35		6.73	
E1	4.32			
е		2.286		
e1		4.572		
Н	9.94		10.34	
L	1.50		1.78	
L1		2.74		
L2	0.89		1.27	
L4			1.02	

Figure 28: DPAK (TO-252) type E recommended footprint (dimensions are in mm)



4.2.4 DPAK (TO-252) packing information

Figure 29: DPAK (TO-252) tape outline



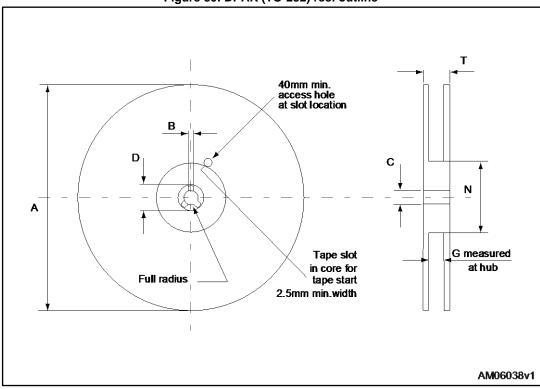


Figure 30: DPAK (TO-252) reel outline

Table 14: DPAK (TO-252) tape and reel mechanical data

Таре		Reel				
Dim.	mm		Dim	r	mm	
Dilli.	Min.	Max.	Dim.	Min.	Max.	
A0	6.8	7	А		330	
B0	10.4	10.6	В	1.5		
B1		12.1	С	12.8	13.2	
D	1.5	1.6	D	20.2		
D1	1.5		G	16.4	18.4	
E	1.65	1.85	N	50		
F	7.4	7.6	Т		22.4	
K0	2.55	2.75				
P0	3.9	4.1	Bas	se qty.	2500	
P1	7.9	8.1	Bulk qty. 250		2500	
P2	1.9	2.1				
R	40					
Т	0.25	0.35				
W	15.7	16.3				

4.3 TO-220FP package information

Figure 31: TO-220FP package outline

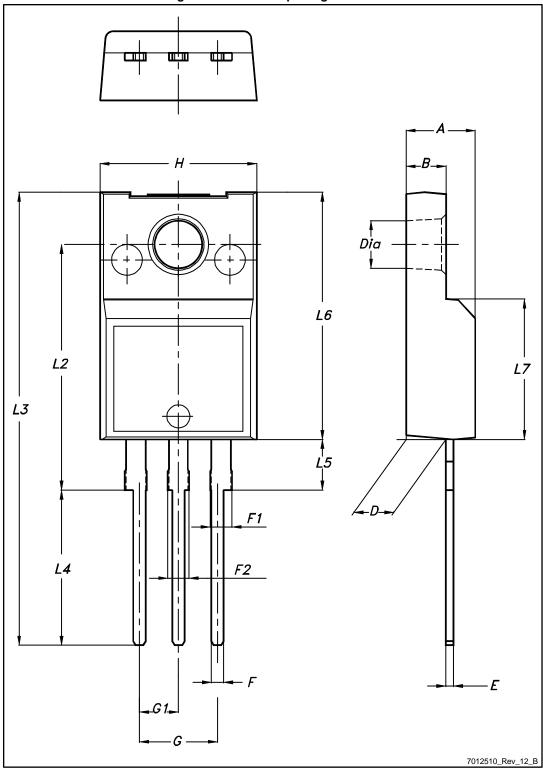


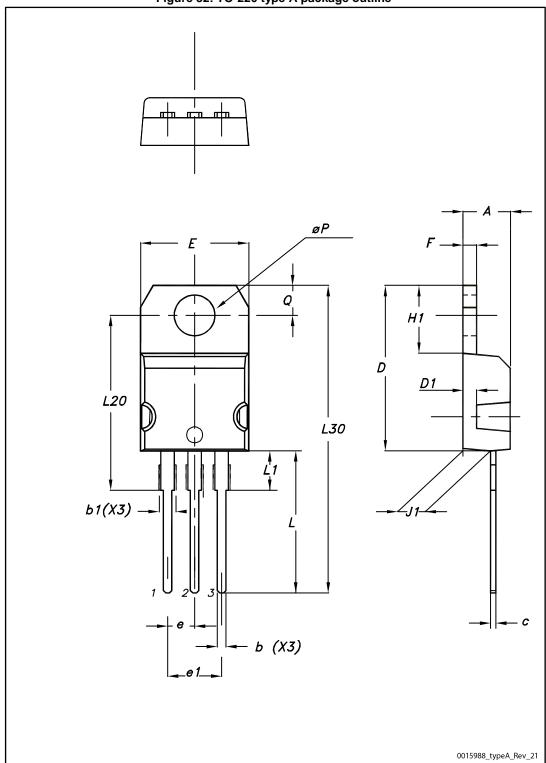
Table 15: TO-220FP package mechanical data

Table 13. 10-22011 package mechanical data			
Dim.		mm	
	Min.	Тур.	Max.
А	4.4		4.6
В	2.5		2.7
D	2.5		2.75
Е	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
Н	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

4.4 TO-220 package information

4.4.1 TO-220 type A package information

Figure 32: TO-220 type A package outline



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Table 16: TO-220 type A mechanical data

Table 16. 10-220 type A mechanical data				
Dim.	mm			
	Min.	Тур.	Max.	
Α	4.40		4.60	
b	0.61		0.88	
b1	1.14		1.55	
С	0.48		0.70	
D	15.25		15.75	
D1		1.27		
E	10.00		10.40	
е	2.40		2.70	
e1	4.95		5.15	
F	1.23		1.32	
H1	6.20		6.60	
J1	2.40		2.72	
L	13.00		14.00	
L1	3.50		3.93	
L20		16.40		
L30		28.90		
øΡ	3.75		3.85	
Q	2.65		2.95	

4.4.2 TO-220 type H package information

Figure 33: TO-220 type H package outline

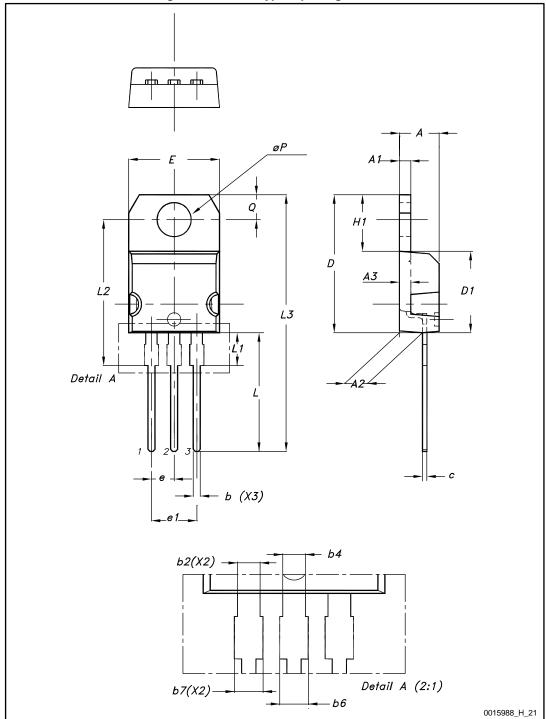


Table 17: TO-220 type H package mechanical data

		mm	
Dim.	Min.	Тур.	Max.
А	4.40	4.45	4.50
A1	1.22		1.32
A2	2.49	2.59	2.69
A3	1.17	1.27	1.37
b	0.78		0.87
b2	1.25		1.34
b4	1.20		1.29
b6			1.50
b7			1.45
С	0.49		0.56
D	15.40	15.50	15.60
D1	9.05	9.15	9.25
E	10.08	10.18	10.28
е	2.44	2.54	2.64
e1	4.98	5.08	5.18
H1	6.25	6.35	6.45
L	13.20	13.40	13.60
L1	3.50	3.70	3.90
L2	16.30	16.40	16.50
L3	28.70	28.90	29.10
ØР	3.75	3.80	3.85
Q	2.70	2.80	2.90

5 Revision history

Table 18: Document revision history

Date	Revision	Changes
09-Sep-2004	3	Complete document
10-Aug-2006	4	New template, no content change
26-Feb-2009	5	Updated mechanical data
07-Sep-2009	6	V _{ESD(G-S)} value has been corrected
06-Apr-2017	7	Updated Section 1: "Electrical ratings", Section 2: "Electrical characteristics" and Section 4: "Package information". Minor text changes



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